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For Express Mail Only: 4642 NW 12th Place, Gainesville, FL 32605, USA
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H. Kawazoe, Tokyo Institute of Technology, Materials and Structures Laboratory, 4259 Nagatsuta, Midori-ku, Yokohama 226, Japan

Kenneth Kelton, Department of Physics, Washington University, Box 1105, One Brookings Drive, St. Louis, MO 63130, USA

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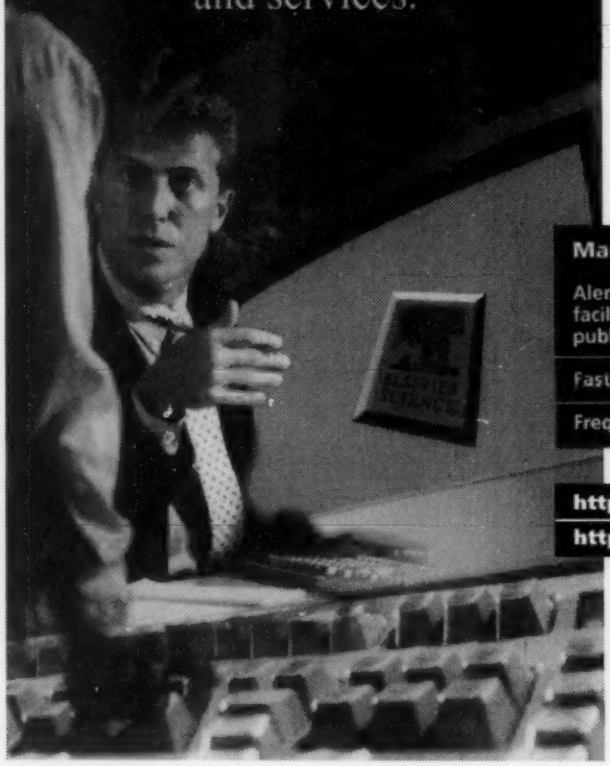

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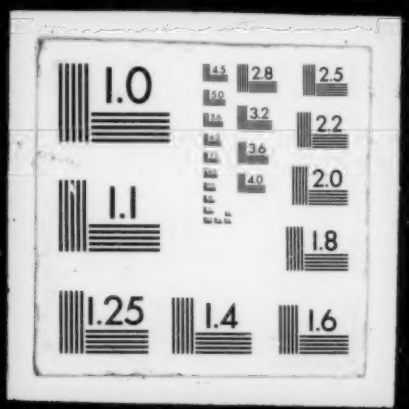
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